TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX04F,TC74LCX04FN,TC74LCX04FT

Low-Voltage Hex Inverter with 5-V Tolerant Inputs and Outputs

The TC74LCX04F/FN/FT is a high-performance CMOS inverter. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

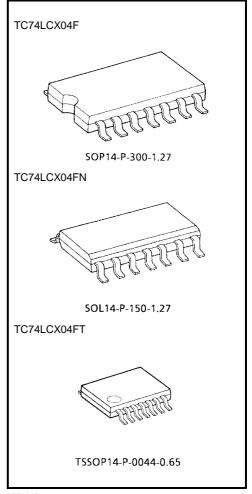
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

Features

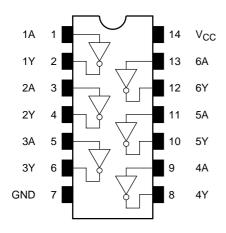
- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 5.2 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 04 type

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight SOP14-P-300-1.27: 0.18 g (typ.) SOL14-P-150-1.27: 0.12 g (typ.) TSSOP14-P-0044-0.65: 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

4.0	1		L	2	41/
1A -	3	1		4	- 1Y
2A -	5	•		6	- 2Y
3A -	9			8	- 3Y
4A -	11	•		10	4Y
5A -	13			12	5Y
6A -			\vdash		- 6Y

Truth Table

Inputs	Outputs
Α	Υ
L	Н
Н	L

Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5	V
		(Note 2)	
Input diode current	lık	-50	mA
Output diode current	lok	±50 (Note 3)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: $V_{CC} = 0 V$

Note 2: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Davier avealuveltana	V	2.0 to 3.6	٧	
Power supply voltage	Vcc	1.5 to 3.6 (Note 4)		
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V	0 to 5.5 (Note 5)	V	
Output voltage	V _{OUT}	0 to V _{CC} (Note 6)		
Output current	I _{OH} /I _{OI}	±24 (Note 7)	mA	
Output current	IOH/IOL	±12 (Note 8)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 9)	ns/V	

Note 4: Data retention only

Note 5: $V_{CC} = 0 V$

Note 6: High or low state

Note 7: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 8: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 9: $V_{IN} = 0.8 \text{ to } 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition		Min	Max	Unit	
Characteris	otioo	Cymbol	1031 00	manion	V _{CC} (V)		Max	Offic
Output voltage	H-level	V _{IH}	_	_		2.0	_	V
	_	_	2.7 to 3.6	_	8.0	v		
			$V_{IN} = V_{IL}$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -18 \text{ mA}$ $I_{OH} = -24 \text{ mA}$	2.7 to 3.6	V _{CC} - 0.2	_		
	H-level	Voh		$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2		V
	L-level V	Voi	V _{IN} = V _{IH}	$I_{OL} = 100 \mu A$	2.7 to 3.6	_	0.2	
				$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
		VOL		I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
Power-off leakage current		loff	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μΑ
Quiescent supply current		Icc	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	10.0	
			V _{IN} = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μΑ
Increase in Icc per input		Δlcc	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6	_	500	

3



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	6.0	ns
Tropagation delay time	t_{pHL}		3.3 ± 0.3	1.5	5.2	
Output to output skew	t _{osLH}	(Note 10)	2.7	_	_	ns
Output to output skew	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	

Note 10: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	٧
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		3.3	7	pF
Output capacitance	C _{OUT}			0	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$	(Note 11)	3.3	25	pF

Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/6 (per gate)

AC Test Circuit

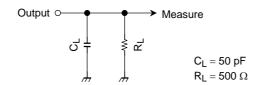


Figure 1

AC Waveform

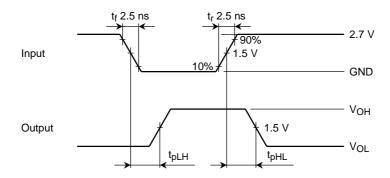
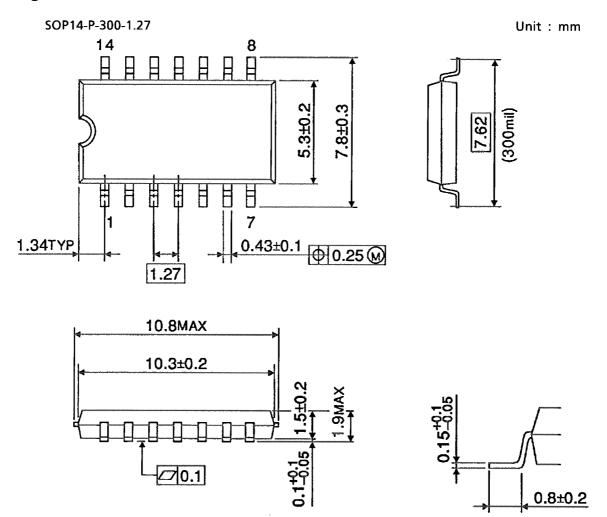


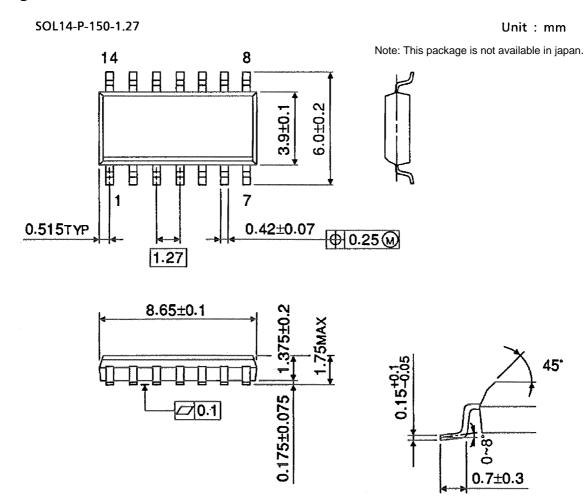
Figure 2 t_{pLH}, t_{pHL}

Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions

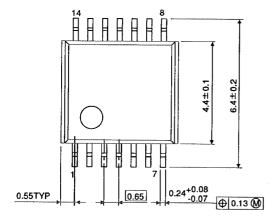


Weight: 0.12 g (typ.)

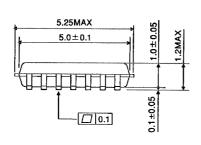
Unit: mm

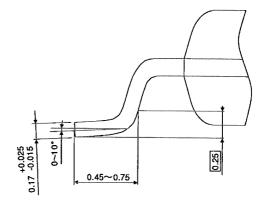
Package Dimensions

TSSOP14-P-0044-0.65









Weight: 0.06 g (typ.)

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